## 2N3905 2N3906

# PNP SILICON TRANSISTOR

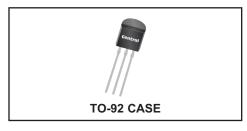


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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N3905 and 2N3906 types are PNP silicon transistors designed for general purpose amplifier and switching applications. NPN complementary types are 2N3903 and 2N3904.





| MAXIMUM RATINGS: (TA=25°C)                 | SYMBOL                            |             | UNITS |
|--|-----------------------------------|-------------|-------|
| Collector-Base Voltage                     | $V_{CBO}$                         | 40          | V     |
| Collector-Emitter Voltage                  | $V_{CEO}$                         | 40          | V     |
| Emitter-Base Voltage                       | $V_{EBO}$                         | 5.0         | V     |
| Continuous Collector Current               | l <sub>C</sub>                    | 200         | mA    |
| Power Dissipation                          | $P_{D}$                           | 625         | mW    |
| Operating and Storage Junction Temperature | T <sub>J</sub> , T <sub>stg</sub> | -65 to +150 | °C    |
| Thermal Resistance                         | $\Theta_{JA}$                     | 200         | °C/W  |

|                       | CHARACTERISTICS: (T <sub>A</sub> =25°C)  | 2N3  |                  | 2N3  |                  | LINUTO |
|-----------------------|--|------|------------------|------|------------------|--------|
| SYMBOL                | TEST CONDITIONS  | MIN  | <b>MAX</b><br>50 | MIN  | <b>MAX</b><br>50 | UNITS  |
| ICEV                  | V <sub>CE</sub> =30V, V <sub>EB</sub> =3.0V  | -    |                  | -    | 50               | nA     |
| BV <sub>CBO</sub>     | I <sub>C</sub> =10μA   | 40   | -                | 40   | -                | V      |
| BV <sub>CEO</sub>     | I <sub>C</sub> =1.0mA  | 40   | -                | 40   | -                | V      |
| BVEBO                 | I <sub>E</sub> =10μA   | 5.0  | -                | 5.0  | -                | V      |
| VCE(SAT)              | I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  | -    | 0.25             | -    | 0.25             | V      |
| VCE(SAT)              | I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA  | -    | 0.4              | -    | 0.4              | V      |
| V <sub>BE</sub> (SAT) | I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  | 0.65 | 0.85             | 0.65 | 0.85             | V      |
| V <sub>BE</sub> (SAT) | I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA  | -    | 0.95             | -    | 0.95             | V      |
| h <sub>FE</sub> ` ´   | $V_{CE}=1.0V, I_{C}=0.1mA$   | 30   | -                | 60   | -                |        |
| hFE                   | V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA   | 40   | -                | 80   | -                |        |
| hFE                   | $V_{CE}$ =1.0V, $I_{C}$ =10mA  | 50   | 150              | 100  | 300              |        |
| h <sub>FE</sub>       | $V_{CE}$ =1.0V, $I_{C}$ =50mA  | 30   | -                | 60   | -                |        |
| hFE                   | V <sub>CE</sub> =1.0V, I <sub>C</sub> =100mA   | 15   | -                | 30   | -                |        |
| h <sub>fe</sub>       | $V_{CE}$ =10V, $I_{C}$ =1.0mA, f=1.0kHz  | 50   | 200              | 100  | 400              |        |
| f <sub>T</sub>        | $V_{CE}$ =20V, $I_{C}$ =10mA, f=100MHz   | 200  | -                | 250  | -                | MHz    |
| C <sub>ob</sub>       | $V_{CB}$ =5.0V, $I_{E}$ =0, f=100kHz   | -    | 4.5              | -    | 4.5              | pF     |
| C <sub>ib</sub>       | $V_{EB}$ =0.5V, $I_{C}$ =0, f=100kHz   | -    | 10               | -    | 10               | pF     |
| NF                    | $V_{CE}$ =5.0V, $I_{C}$ =100 $\mu$ A, $R_{S}$ =1.0 $k\Omega$                         |      |                  |      |                  |        |
|                       | f=10Hz to 15.7kHz  | -    | 5.0              | -    | 4.0              | dB     |
| ton                   | V <sub>CC</sub> =3.0V, V <sub>BE(OFF)</sub> =0.5V, I <sub>C</sub> =10mA              |      |                  |      |                  |        |
|                       | I <sub>B1</sub> =1.0mA   | -    | 70               | -    | 70               | ns     |
| toff                  | V <sub>CC</sub> =3.0V, I <sub>C</sub> =10mA, I <sub>B1</sub> =I <sub>B2</sub> =1.0mA | -    | 260              | -    | 300              | ns     |

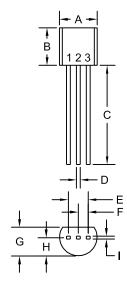
R2 (17-October 2011)

## 2N3905 2N3906

# PNP SILICON TRANSISTOR



# **TO-92 CASE - MECHANICAL OUTLINE**



| DIMENSIONS |        |       |             |      |  |  |
|------------|--------|-------|-------------|------|--|--|
|            | INCHES |       | MILLIMETERS |      |  |  |
| SYMBOL     | MIN    | MAX   | MIN         | MAX  |  |  |
| A (DIA)    | 0.175  | 0.205 | 4.45        | 5.21 |  |  |
| В          | 0.170  | 0.210 | 4.32        | 5.33 |  |  |
| С          | 0.500  | -     | 12.70       | -    |  |  |
| D          | 0.016  | 0.022 | 0.41        | 0.56 |  |  |
| Е          | 0.100  |       | 2.54        |      |  |  |
| F          | 0.050  |       | 1.27        |      |  |  |
| G          | 0.125  | 0.165 | 3.18        | 4.19 |  |  |
| Н          | 0.080  | 0.105 | 2.03        | 2.67 |  |  |
|            | 0.015  |       | 0.38        |      |  |  |

TO-92 (REV: R1)

# LEAD CODE:

- 1) Emitter 2) Base 3) Collector

# MARKING:

R1

**FULL PART NUMBER** 

### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### **CONTACT US**

### Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA

Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

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